



EVERLIGHT ELECTRONICS CO., LTD.

DEVICE NUMBER : DPT-028-028 REV : 1.3
 ECN : _____ PAGE : 1/7

1.3mm Axial Flat Top Phototransistor

MODEL NO : PT28-21C

■ Features :

- Fast response time
- High photo sensitivity

■ Description :

- PT28-21C is a phototransistor in miniature SMD package which is molded in a water clear plastic with flat top view lens. The device is spectrally matched to infrared emitting diode.

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■ Applications :

- Optoelectronic switch
- VCRs ,Video camera
- Floppy disk drive
- Infrared applied system

PART NO.	CHIP	LENS COLOR
	MATERIAL	
PT	Silicon	Water clear

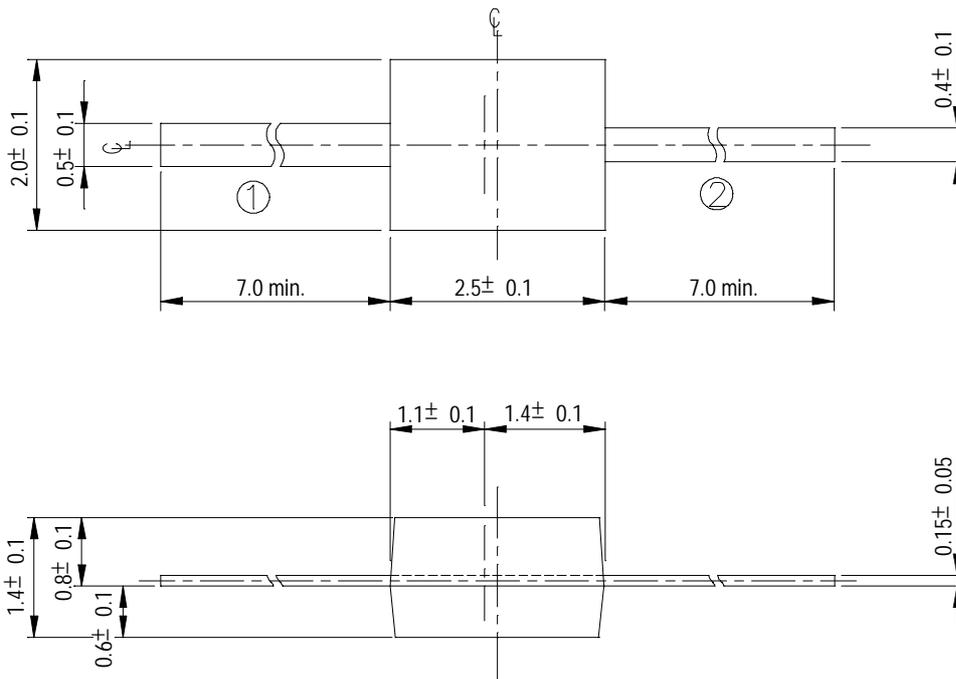


DEVICE NUMBER : DPT-028-028 REV : 1.3
 ECN : _____ PAGE : 2/7

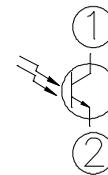
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MODEL NO : PT28-21C

Package Dimensions:



① Collector
 ② Emitter



Notes :

- All dimensions are in millimeter.
- General Tolerance: ± 0.1 mm
- Lens color : Water clear.
- Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
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- When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



EVERLIGHT ELECTRONICS CO., LTD.

DEVICE NUMBER : DPT-028-028 REV : 1.3
 ECN : _____ PAGE : 3/7

1.3mm Axial Flat Top Phototransistor

MODEL NO : PT28-21C

■ Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit	Notice
Collector-Emitter Voltage	V_{CEO}	30	V	
Emitter-Collector- Voltage	V_{ECO}	5	V	
Collector Current	I_C	20	mA	
Operating Temperature	T_{opr}	-25 ~ +85	$^\circ\text{C}$	
Storage Temperature	T_{stg}	-40 ~ +85	$^\circ\text{C}$	
Soldering Temperature	T_{sol}	260	$^\circ\text{C}$	
Power Dissipation at(or below) 25 $^\circ\text{C}$ Free Air Temperature	P_c	75	mW	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-Emitter Breakdown Voltage	BV_{CEO}	30	----	----	V	$I_C=100\mu\text{A}$ $E_e=0\text{mW}/\text{cm}^2$
Emitter-Collector Breakdown Voltage	BV_{ECO}	5	----	----	V	$I_E=100\mu\text{A}$ $E_e=0\text{mW}/\text{cm}^2$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	----	----	0.4	V	$I_C=2\text{mA}$ $E_e=1\text{mW}/\text{cm}^2$
Rise Time	t_r	----	15	----	μS	$V_{CE}=5\text{V}$ $I_C=1\text{mA}$ $R_L=1000\Omega$
Fall Time	t_f	----	15	----		
Collector Dark Current	I_{CEO}	----	----	100	nA	$V_{CE}=20\text{V}$ $E_e=0\text{mW}/\text{cm}^2$
On State Collector Current	$I_{C(on)}$	0.1	0.3	----	mA	$V_{CE}=5\text{V}$ $E_e=1\text{mW}/\text{cm}^2$
Wavelength of Peak Sensitivity	λ_p	----	980	----	nm	----
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	400---1200	----	nm	----



DEVICE NUMBER : DPT-028-028
 ECN : _____

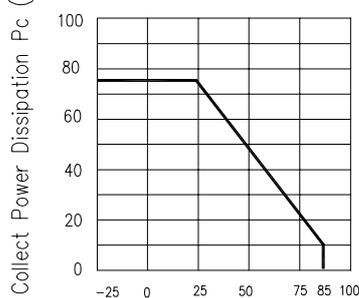
REV : 1.3
 PAGE : 4/7

1.3mm Axial Flat Top Phototransistor

MODEL NO : PT28-21C

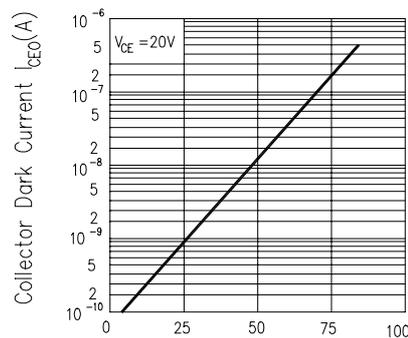
Typical Electrical/Optical/Characteristics Curves

Fig.1 Collector Power Dissipation vs. Ambient Temperature



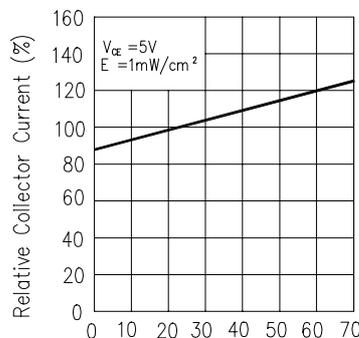
Ambient Temperature T_a (°C)

Fig.2 Collector Dark Current vs. Ambient Temperature



Ambient Temperature T_a (°C)

Fig. 3 Relative Collector Current vs. Ambient Temperature



Ambient Temperature T_a (°C)

Fig.4 Collector Current vs. Irradiance

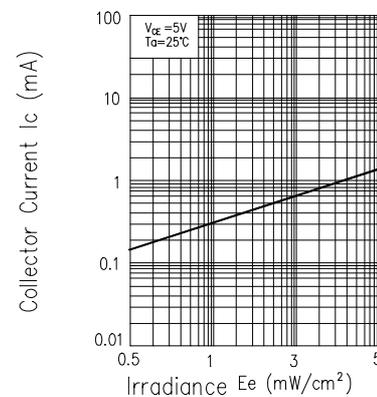
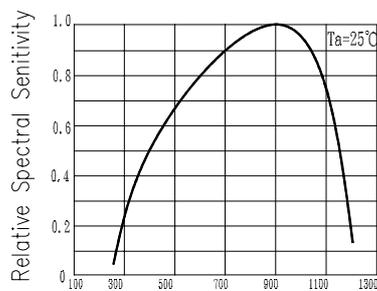
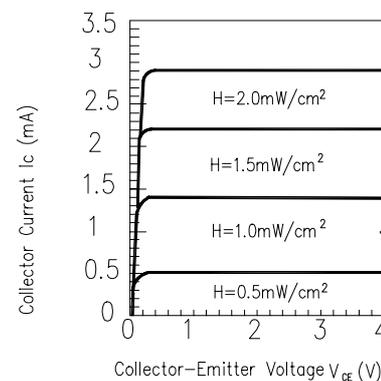


Fig.5 Spectral Sensitivity



Wavelength λ (nm)

Fig.6 Collector Current vs. Collector-Emitter Voltage



Collector-Emitter Voltage V_{CE} (V)



EVERLIGHT ELECTRONICS CO., LTD.

 DEVICE NUMBER : DPT-028-028 REV : 1.3

 ECN : _____ PAGE : 5/7

1.3mm Axial Flat Top Phototransistor

 MODEL NO : PT28-21C

■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	5 secs	22 pcs		0/1
2	Temperature Cycle	H : +85°C 30 mins ↑ 5 mins ↓ L : -55°C 30 mins	50 cycles	22 pcs	$I_R \geq U \times 2$ $E_e \leq L \times 0.8$ $V_F \geq U \times 1.0$	0/1
3	Thermal Shock	H : +100°C 5 mins ↑ 10 secs ↓ L : -10°C 5 mins	50 cycles	22 pcs	U :Upper specification limit L :Lower specification limit	0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 pcs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000 hrs	22 pcs		0/1
6	DC Operating Life	$I_F = 20\text{mA}$	1000 hrs	22 pcs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 pcs		0/1



DEVICE NUMBER : DPT-028-028
ECN : _____

REV : 1.3
PAGE : 6/7

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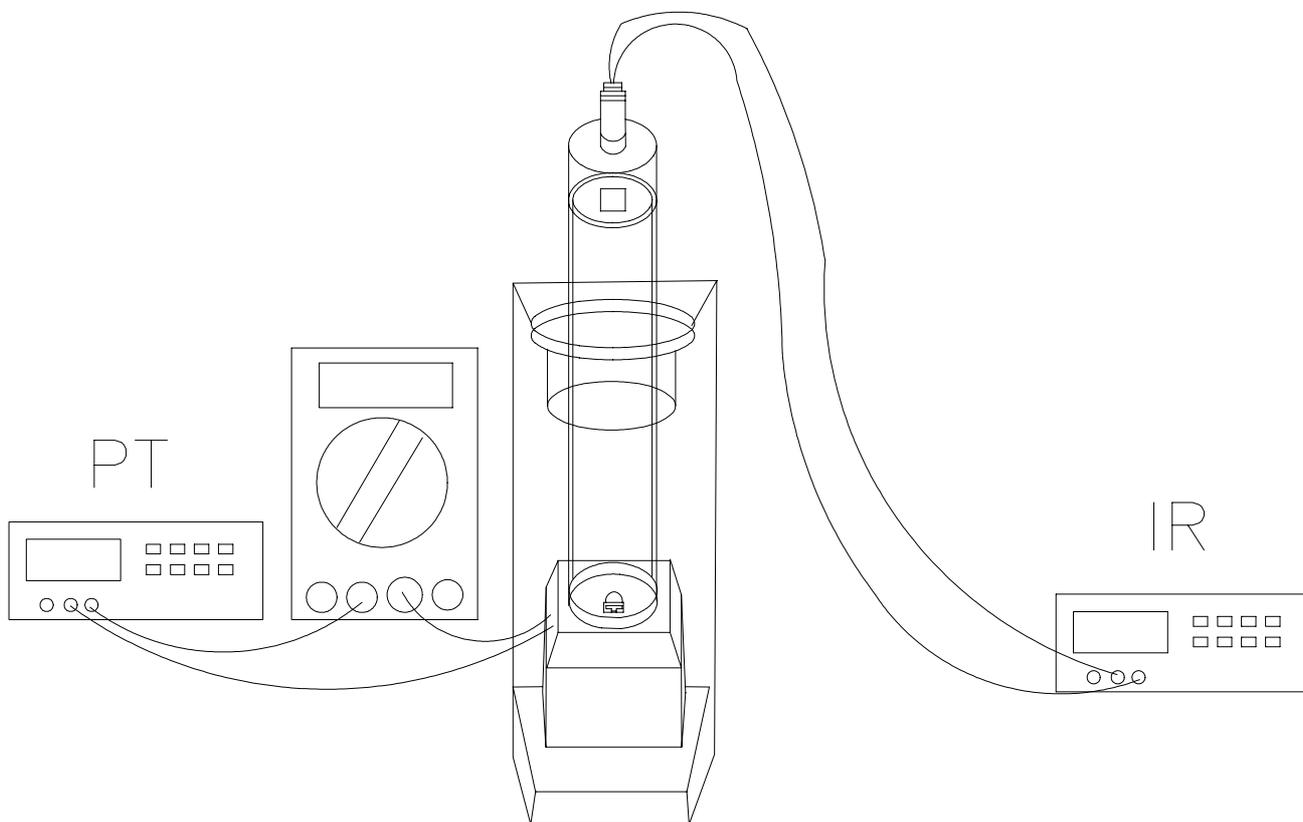
MODEL NO : PT28-21C

■ Test Method For On State Collector Current :

Condition : $E_e=1\text{mW/cm}^2$, $V_{CE}=5\text{V}$

Test Item : Collector Current [$I_{C(on)}$]

Unit : mA





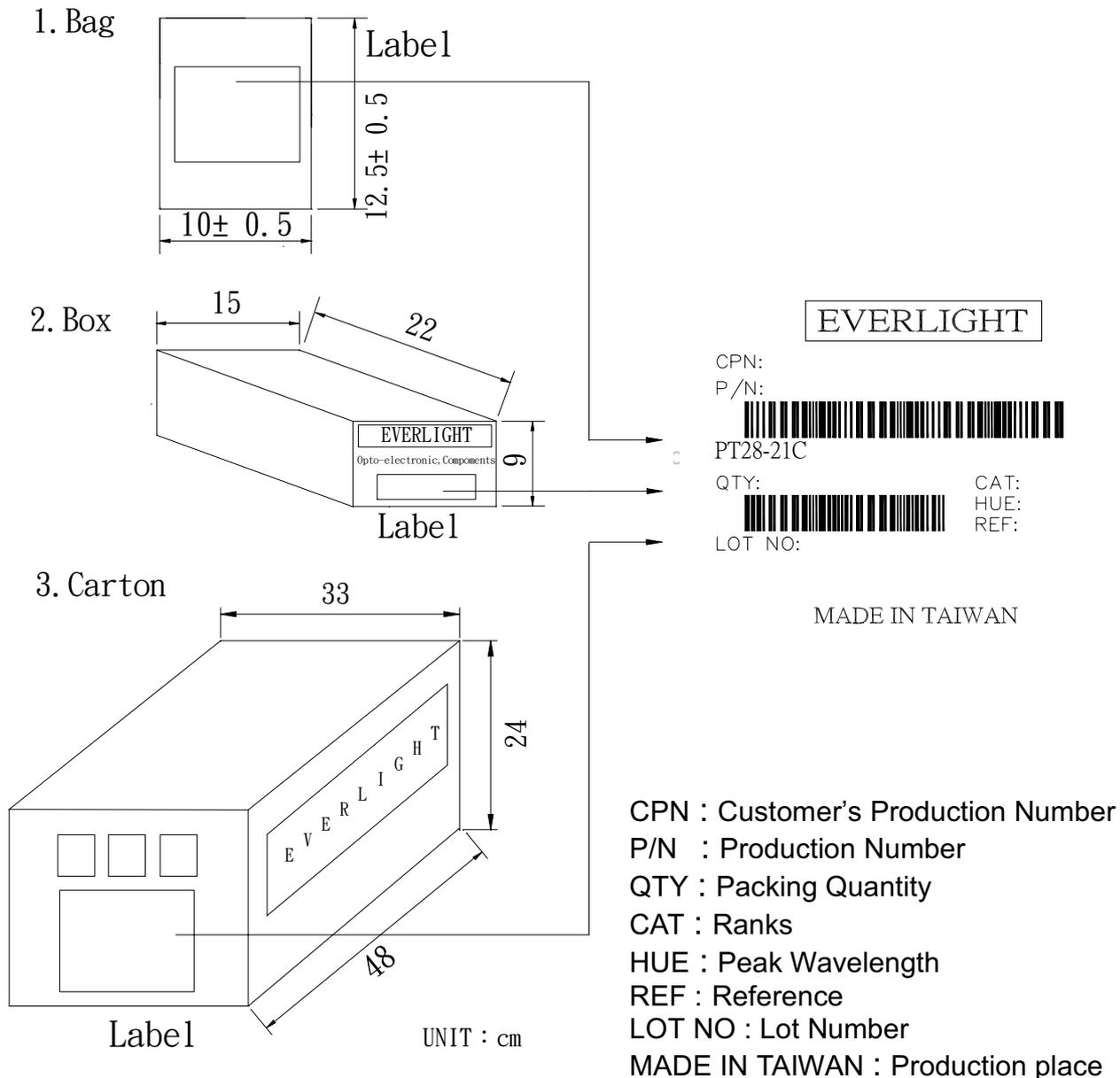
EVERLIGHT ELECTRONICS CO., LTD.

DEVICE NUMBER : DPT-028-028 REV : 1.3
 ECN : _____ PAGE : 7/7

1.3mm Axial Flat Top Phototransistor

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■ Packing Specifications



■ Packing Quantity Specification

1. 1000 Pcs/1Bag , 20 Bags/1Box
2. 10 Boxes/1Carton

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